

International **IR** Rectifier

8ETH06PbF 8ETH06FPPbF

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- 2500V insulation voltage ③
- UL E78996 approved 
- Lead-Free ("PbF")

$t_{rr} = 18\text{ns typ.}$ $I_{F(AV)} = 8\text{Amp}$ $V_R = 600\text{V}$

Description/Applications

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, Hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

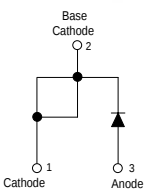
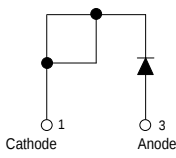
These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	600	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 144^\circ\text{C}$ @ $T_C = 108^\circ\text{C}$ (FULLPACK)	8	A
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$ (FULLPACK)	90 100	
I_{FM} Peak Repetitive Forward Current	16	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

Case Styles

8ETH06PbF   TO-220AC	8ETH06FPPbF   TO-220 FULLPACK
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Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}, V_R Breakdown Voltage, Blocking Voltage	600	-	-	V	$I_R = 100\mu\text{A}$
V_F Forward Voltage	-	2.0	2.4	V	$I_F = 8\text{A}, T_J = 25^\circ\text{C}$
	-	1.3	1.8	V	$I_F = 8\text{A}, T_J = 150^\circ\text{C}$
I_R Reverse Leakage Current	-	0.3	50	μA	$V_R = V_R$ Rated
	-	55	500	μA	$T_J = 150^\circ\text{C}, V_R = V_R$ Rated
C_T Junction Capacitance	-	17	-	pF	$V_R = 600\text{V}$
L_S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_C = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr} Reverse Recovery Time	-	18	22	ns	$I_F = 1\text{A}, di_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	20	25		$I_F = 8\text{A}, di_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	25	-		$T_J = 25^\circ\text{C}$
	-	40	-		$T_J = 125^\circ\text{C}$
I_{RRM} Peak Recovery Current	-	2.4	-	A	$T_J = 25^\circ\text{C}$
	-	4.8	-		$T_J = 125^\circ\text{C}$
Q_{rr} Reverse Recovery Charge	-	25	-	nC	$T_J = 25^\circ\text{C}$
	-	120	-		$T_J = 125^\circ\text{C}$
t_{rr} Reverse Recovery Time	-	33	-	ns	$I_F = 8\text{A}$ $di_F/dt = 200\text{A}/\mu\text{s}$ $V_R = 390\text{V}$
I_{RRM} Peak Recovery Current	-	12	-	A	
Q_{rr} Reverse Recovery Charge	-	220	-	nC	

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T_J Max. Junction Temperature Range	-	-	175	$^\circ\text{C}$
T_{Stg} Max. Storage Temperature Range	- 65	-	175	
R_{thJC} Thermal Resistance, Junction to Case Per Leg (Fullpack) Per Leg	-	1.4	2	$^\circ\text{C}/\text{W}$
	-	3.4	4.3	
R_{thJA} ① Thermal Resistance, Junction to Ambient Per Leg	-	-	70	
R_{thCS} ② Thermal Resistance, Case to Heatsink	-	0.5	-	
Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

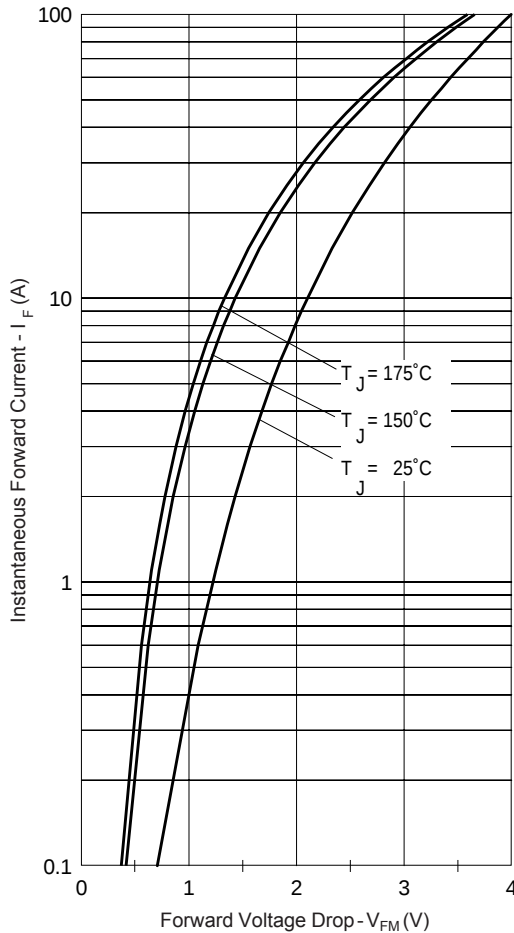


Fig. 1 - Typical Forward Voltage Drop Characteristics

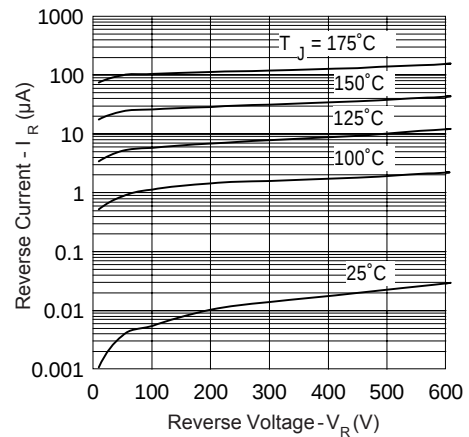


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

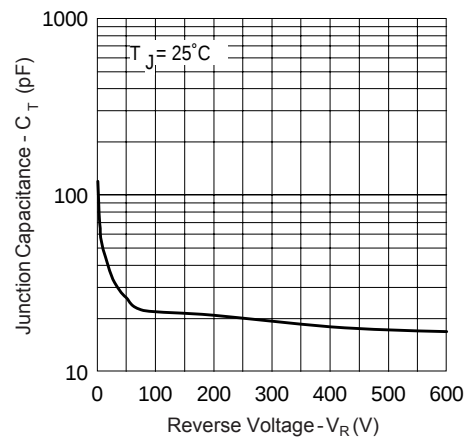


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

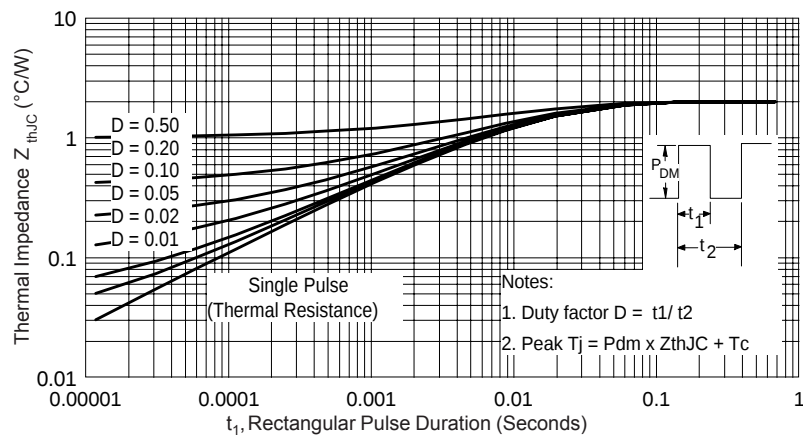


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

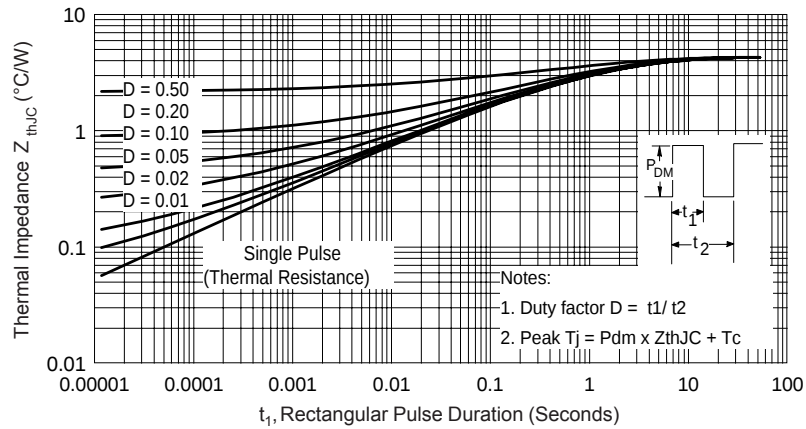
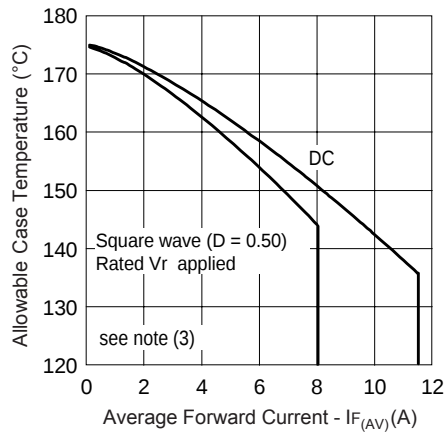
Fig. 5 - Max. Thermal Impedance Z_{thJC} Characteristics (FULLPACK)

Fig. 6 - Max. Allowable Case Temperature Vs. Average Forward Current

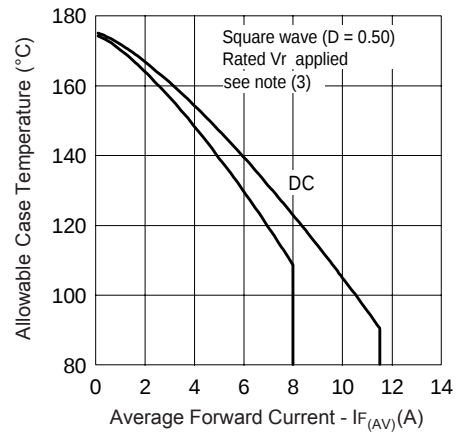


Fig. 7 - Max. Allowable Case Temperature Vs. Average Forward Current (FULLPACK)

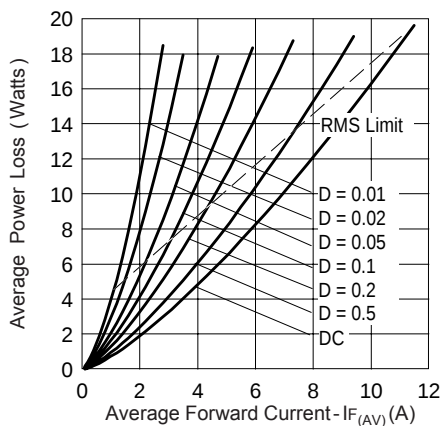


Fig. 8 - Forward Power Loss Characteristics

(3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$

P_d = Forward Power Loss =

$$I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$$

(see Fig. 8);

$$P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D);$$

$$I_R @ V_{R1} = \text{rated } V_R$$

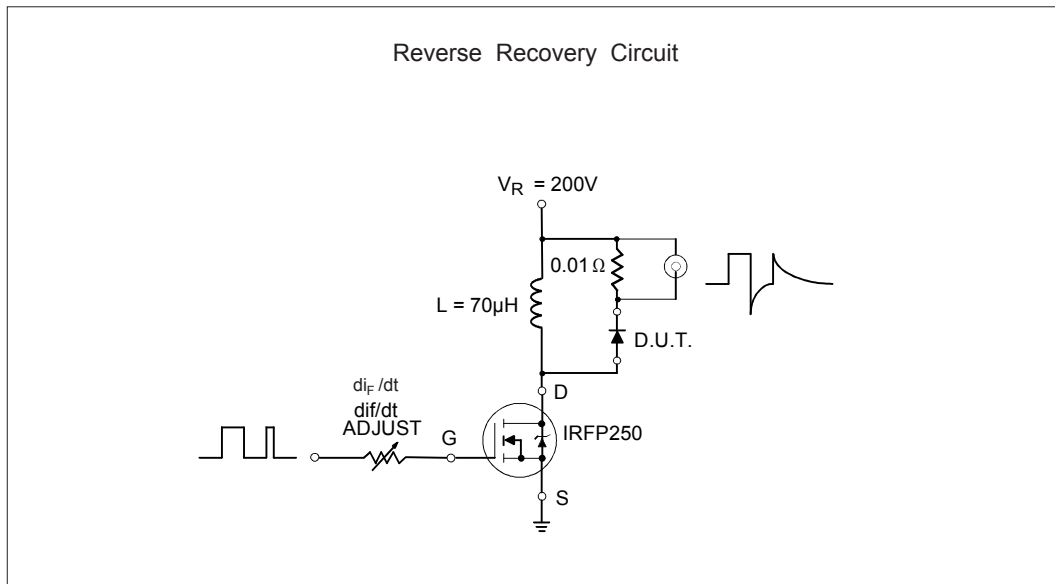
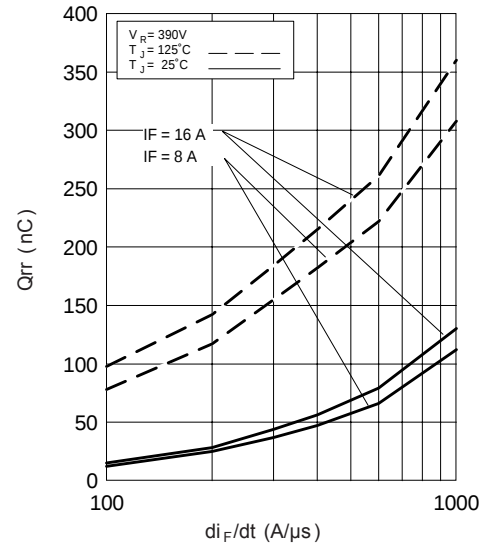
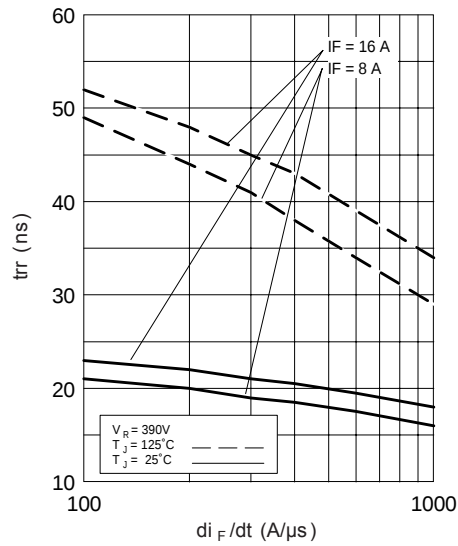


Fig. 11- Reverse Recovery Parameter Test Circuit

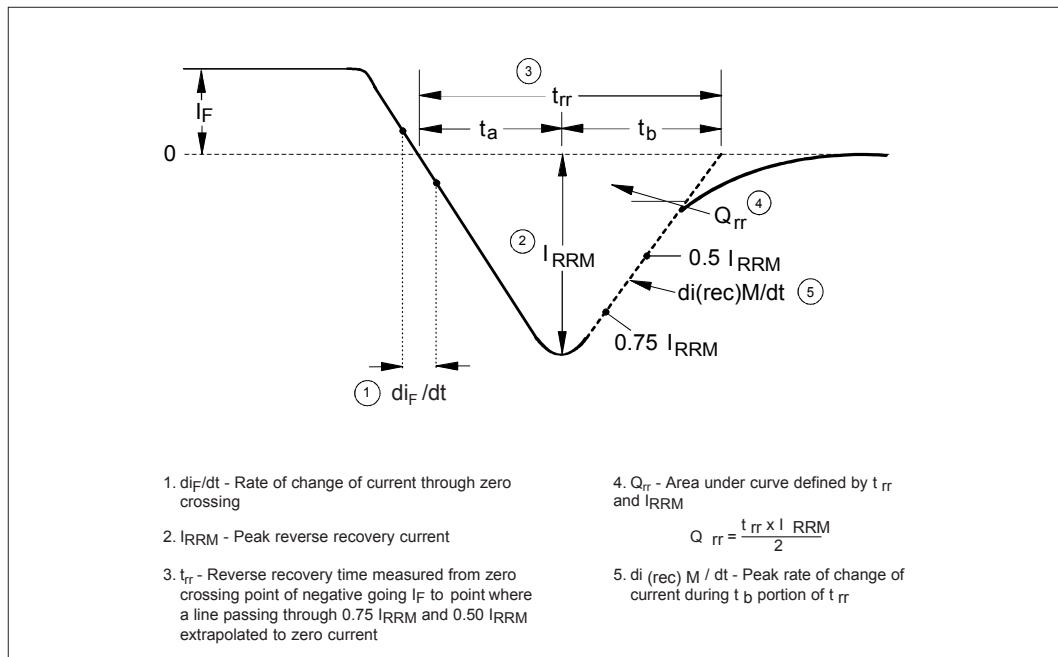
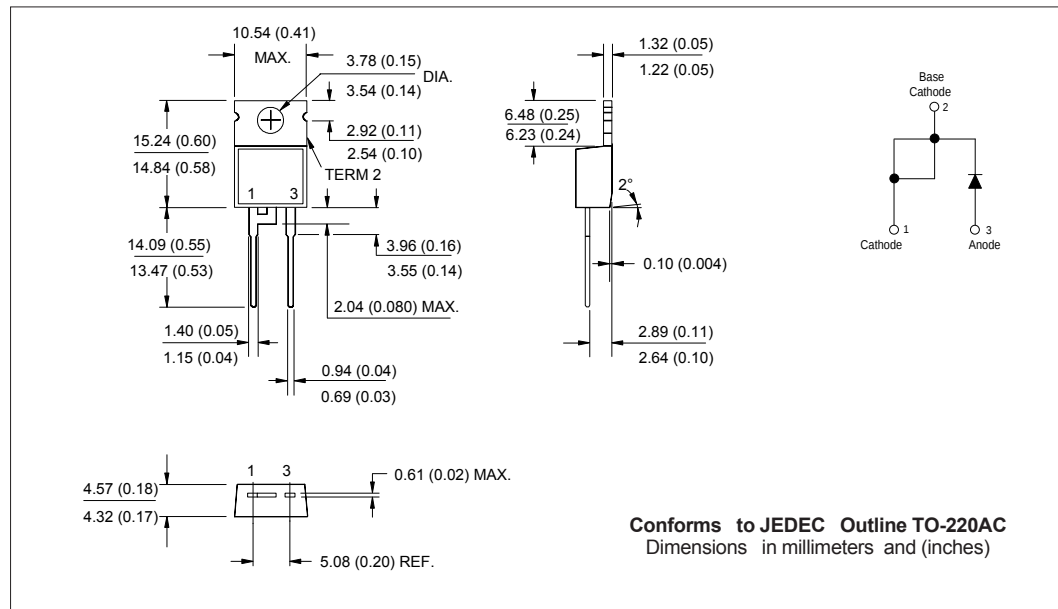
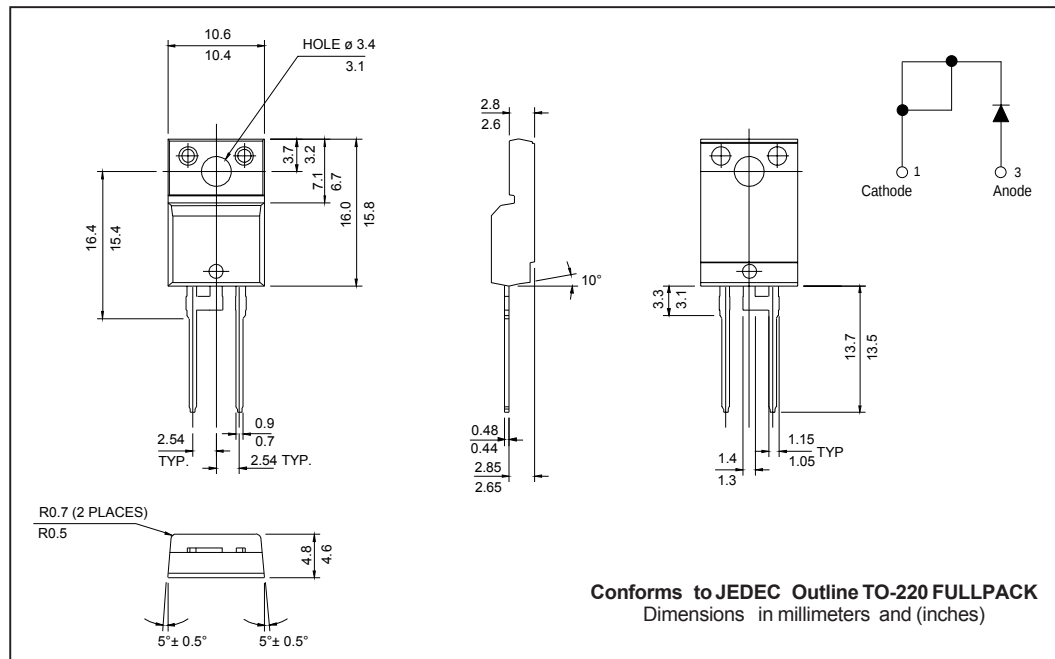


Fig. 12 - Reverse Recovery Waveform and Definitions

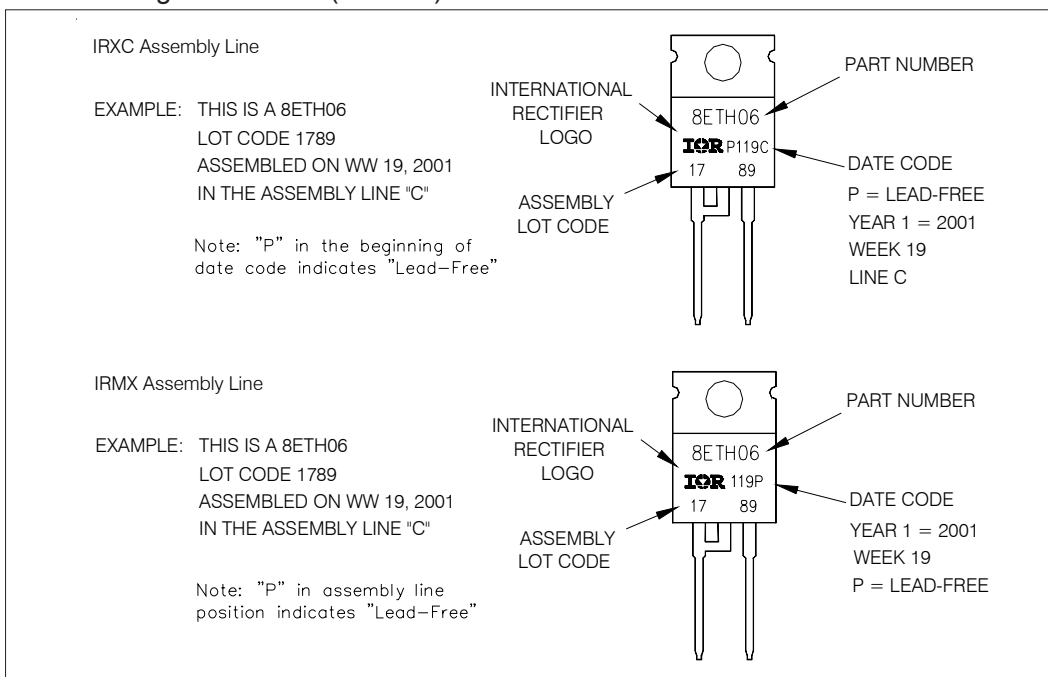
Outline Table



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Part Marking Information (TO-220)



Part Marking Information (TO-220 FULL-PAK)

EXAMPLE: THIS IS A 8ETH06FP
LOT CODE 1789
ASSEMBLED ON WW 19, 2002
IN THE ASSEMBLY LINE "C"

Note: "P" in assembly line
position indicates "Lead-Free"

INTERNATIONAL
RECTIFIER
LOGO

ASSEMBLY
LOT CODE

PART NUMBER
FP = Fullpack

DATE CODE
YEAR = 2002
WEEK 19
P = Lead-Free

Ordering Information Table

Device Code						
8	E	T	H	06	FP	PbF
1	2	3	4	5	6	7
1	2	3	4	5	6	7
1	-	Current Rating (8 = 8A)				
2	-	E = Single Diode				
3	-	T = TO-220, D ² Pak				
4	-	H = HyperFast Recovery				
5	-	Voltage Rating (06 = 600V)				
6	-	• none = TO-220AC • FP = TO-220 FULLPACK				
7	-	• none = Standard Production • PbF = Lead-Free				

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.